



450V NPN HIGH VOLTAGE POWER TRANSISTOR

Features

- BV_{CEO} > 450V
- BV_{CES} > 700V
- BV_{EBO} > 9V
- I_C = 1.5A High Continuous Collector Current
- Integrated Collector-Emitter Diode to Act as Free-wheeling Diode
- · Anti-saturation for Faster Switching
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

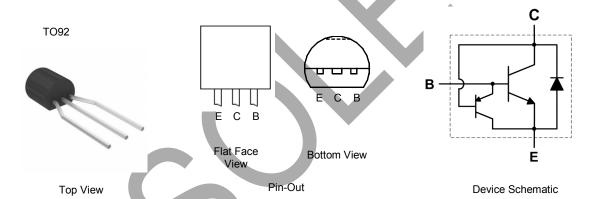
Mechanical Data

- Case: TO92 (Type C)
- Case Material: Molded Plastic, "Green" Molding Compound;
 UL Flammability Classification Rating 94V-0
- Terminals: Matte Tin Finish; Solderable per MIL-STD-202, Method 208 (3)
- Weight: TO92: 200mg (Approximate)

Applications

Low Power AC-DC SMPS for:

- Battery Chargers for Mobile Phone / Tablets / Smartphones
- Power Supply for DVD / STB
- LED Lighting



Ordering Information (Note 4)

Product	Package	Marking	Quantity
APT13003DZTR-G1	TO92 (Joggled Legs)	13003DZ-G1	2,000 Taped, per Ammo Box

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



= Manufacturers' code marking
For TO92, 13003DZ-G1 = Product Type Marking ID
YWW = Date Code Marking
e.g. 312 = Year 2013, Week 12.
8 = Assembly site code
XX = Batch Number

APT13003D Datasheet Number: DS36347 Rev. 4 - 4 1 of 5 www.diodes.com



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage (V _{BE} = 0V)	V _{CES}	700	V
Collector-Emitter Voltage	V _{CEO}	450	V
Emitter-Base Voltage	V _{EBO}	9	V
Continuous Collector Current	I _C	1.5	Α
Peak Pulse Collector Current	I _{CM}	3	Α
Continuous Base Current	I _B	0.75	A
Peak Pulse Base Current	I _{BM}	1.5	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

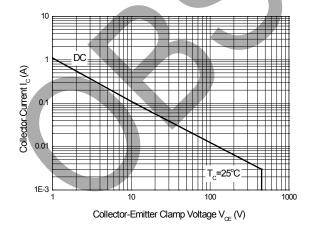
Characteristic	Symbol	Value	Unit
Power Dissipation	P_{D}	1.1	W
Thermal Resistance, Junction to Ambient Air	Reja	113.6	°C/W
Thermal Resistance, Junction to Case	R _{eJC}	83.3	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-65 to +150	°C

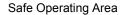
ESD Ratings (Note 5)

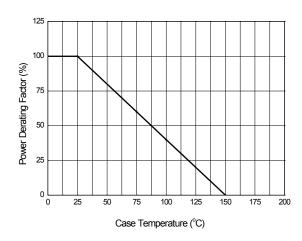
Characteristic	Symbol		Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM		8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM)-	400	V	С

Note: 5. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Safe Operating Areas and Derating Information (@T_A = +25°C, unless otherwise specified.)







Power Derating Curve

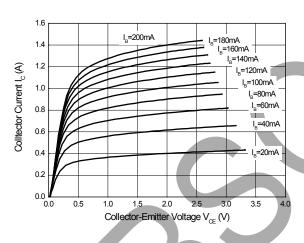


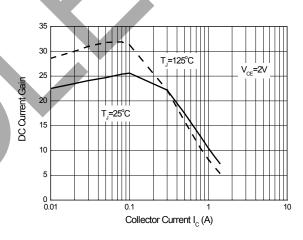
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

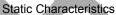
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Emitter Breakdown Voltage	BV _{CES}	700	-	=	V	$I_C = 100 \mu A, V_{BE} = 0 V$
Collector-Emitter Breakdown Voltage	BV _{CEO}	450	-	-	V	I _C = 100μA
Emitter-Base Breakdown Voltage	BV _{EBO}	9	-	_	V	I _E = 100μA
Collector Cutoff Current	I _{CEV}	-	-	10	μΑ	$V_{CE} = 700V, V_{BE} = -1.5V$
DC Current Transfer Static Ratio (Note 6)	b	16	-	30		I _C = 0.5A, V _{CE} = 2V
DC Current Transfer Static Ratio (Note 6)	h _{FE}	5.0	-	25	_	I _C = 1.0A, V _{CE} = 2V
Collector-Emitter Saturation Voltage (Note 6)	V	_	-	0.3	V	$I_C = 0.5A$, $I_B = 0.1A$
Collector-Entitler Saturation Voltage (Note 0)	V _{CE(sat)}	_	-	0.4	V	$I_C = 1A$, $I_B = 0.25A$
Base-Emitter Saturation Voltage (Note 6)	\/	_	-	1.0	V	$I_C = 0.5A$, $I_B = 0.1A$
Base-Emiller Saturation voltage (Note o)	V _{BE(sat)}	_	_	1.2	V	$I_C = 1A$, $I_B = 0.25A$
Output Capacitance	C_{obo}	_	18	-	pF	$V_{CB} = 10V, f = 0.1MHz$
Transition Frequency	f _T	4	-	-	MHz	I _C = 0.1A, V _{CE} = 10V
Turn-on Time with Resistive Load	t _{on}	-	-	0.7		1 44 1/ 4051/ 1 0.04
Storage Time with Resistive Load	ts	-	-	3.0	μs	$I_C = 1A$, $V_{CC} = 125V$, $I_{B1} = 0.2A$,
Fall Time with Resistive Load	t _f	=	-	0.35		$I_{B2} = -0.2A$

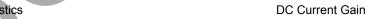
Note: 6. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

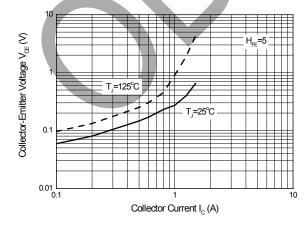
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

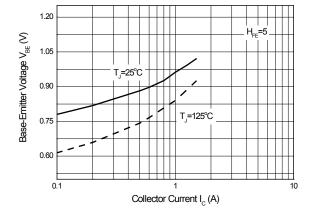












Collector-Emitter Saturation Region

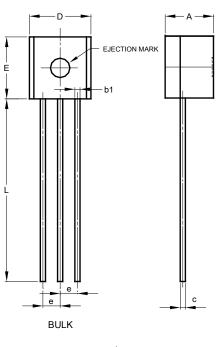
Base-Emitter Saturation Voltage

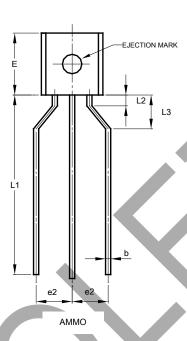


Package Outline Dimensions

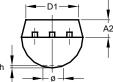
Please see http://www.diodes.com/package-outlines.html for the latest version.

TO92 (Type C)





TO92 (Type C)						
Dim	Min	Max	Тур			
Α	3.30	3.70	-			
A2	1.10	1.40	-			
b	0.38	0.55	-			
C	0.36	0.51	-			
b	4.40	4.70	-			
D1	3.430	1	-			
E	4.30	4.70	-			
е	1	1	1.27			
e2	2.440	2.640	-			
h	0.00	0.38	-			
L	14.10	14.50	-			
L1	12.50	14.50	-			
L3	2.50	3.50	-			
Ø	-	1.60	-			
All Dimensions in mm						



Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to voltage spacing between terminals.



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